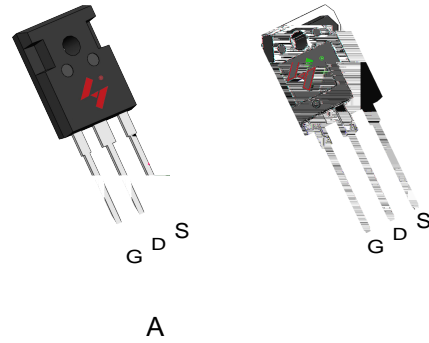


## N-Channel Enhancement Mode MOSFET

### Features

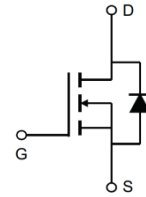
- 80V/360A  
 $R_{DS(ON)} = 1.5 \text{ m}\Omega \text{ (typ.) @ } V_{GS}=10\text{V}$
- 100% avalanche tested
- Reliable and Rugged
- Lead Free and Green Devices Available (RoHS Compliant)

### Pin Description




### Applications

- Switching application
- Power Management for Inverter Systems.



N Channel MOSFET

### Ordering and Marking Information

|   |   |  |
|---|---|--|
|  <b>W</b><br><b>HY5608</b><br>YYXXXJWW G |  <b>A</b><br><b>HY5608</b><br>YYXXXJWW G | Package Code<br>W : TO-247A-3L      A : TO-3P-3L<br><br>Date Code              Assembly Material<br>YYXXX WW              G : Lead Free Device |
|---|---|--|

Note: HUAYI lead-free products contain molding compounds/die attach materials and 100% matte tin plate Termination finish; which are fully compliant with RoHS. HUAYI lead-free products meet or exceed the lead-free requirements of IPC/JEDEC J-STD-020 for MSL classification at lead-free peak reflow temperature. HUAYI defines "Green" to mean lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight).

HUAYI reserves the right to make changes, corrections, enhancements, modifications, and improvements to this product and/or to this document at any time without notice.

## Absolute Maximum Ratings

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

1290\*\*

2829\*\*\*

**HY5608**

80

1.5

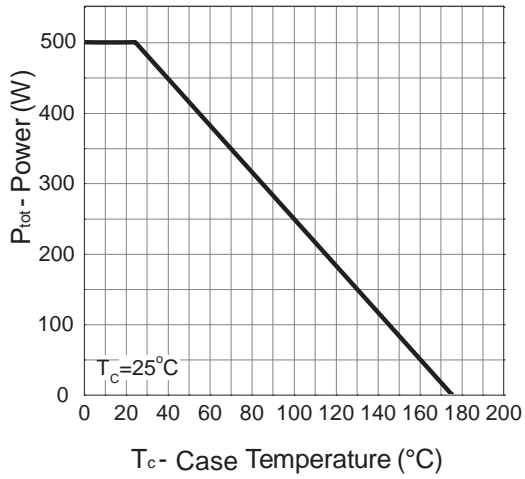
**Electrical Characteristics (Cont.)** ( $T_C = 25^\circ\text{C}$  Unless Otherwise Noted)

| Symbol                             | Parameter                    | Test Conditions  | HY5608 |       |      | Unit     |
|------------------------------------|------------------------------|--|--------|-------|------|----------|
|                                    |                              |  | Min.   | Typ.  | Max. |          |
| <b>Dynamic Characteristics</b>     |                              |  |        |       |      |          |
| $R_G$                              | Gate Resistance              | $V_{GS}=0V, V_{DS}=0V, F=1\text{MHz}$                      | -      | 0.5   | -    | $\Omega$ |
| $C_{iss}$                          | Input Capacitance            | $V_{GS}=0V,$<br>$V_{DS}=25V,$<br>Frequency=1.0MHz          | -      | 14715 | -    | pF       |
| $C_{oss}$                          | Output Capacitance           |  | -      | 1714  | -    |          |
| $C_{rss}$                          | Reverse Transfer Capacitance |  | -      | 853   | -    |          |
| $t_{d(ON)}$                        | Turn-on Delay Time           | $V_{DD}=40V, R_G=6\ \Omega,$<br>$I_{DS}=180A, V_{GS}=10V,$ | -      | 60    | -    | ns       |
| $T_r$                              | Turn-on Rise Time            |  | -      | 47    | -    |          |
| $t_{d(OFF)}$                       | Turn-off Delay Time          |  | -      | 100   | -    |          |
| $T_f$                              | Turn-off Fall Time           |  | -      | 88    | -    |          |
| <b>Gate Charge Characteristics</b> |                              |  |        |       |      |          |
| $Q_g$                              | Total Gate Charge            | $V_{DS}=64V, V_{GS}=10V,$<br>$I_{DS}=180A$                 | -      | 365   | -    | nC       |
| $Q_{gs}$                           | Gate-Source Charge           |  | -      | 55    | -    |          |
| $Q_{gd}$                           | Gate-Drain Charge            |  | -      | 141   | -    |          |

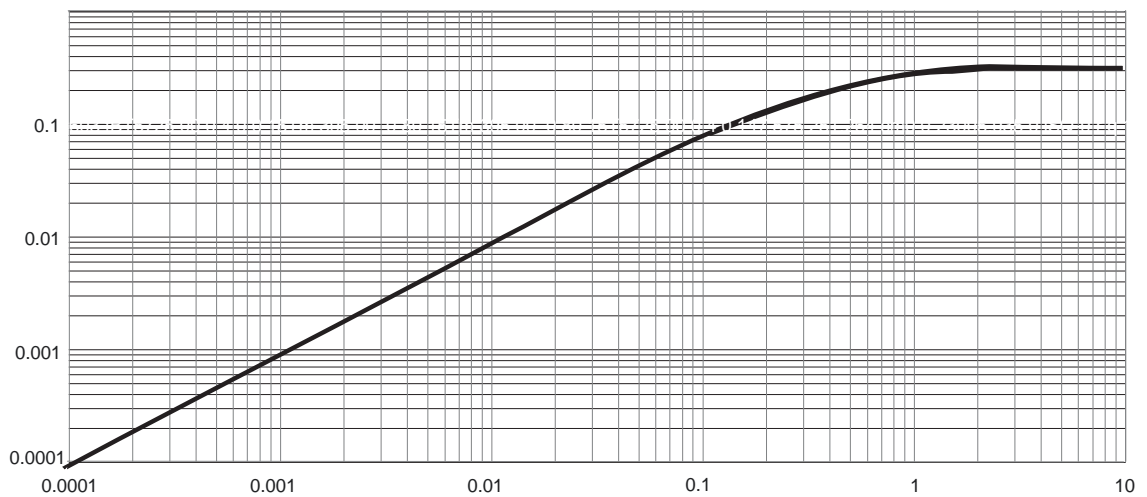
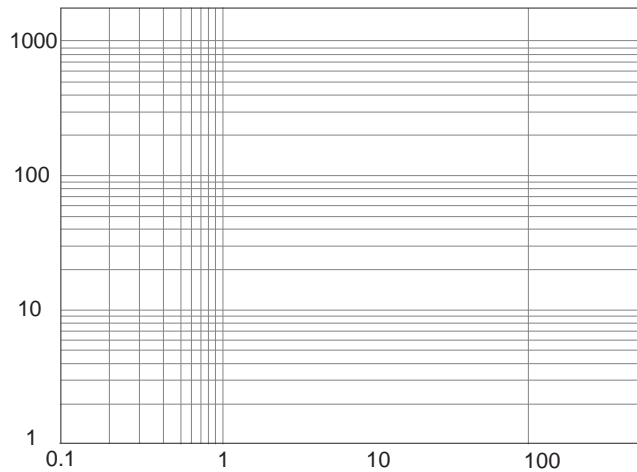
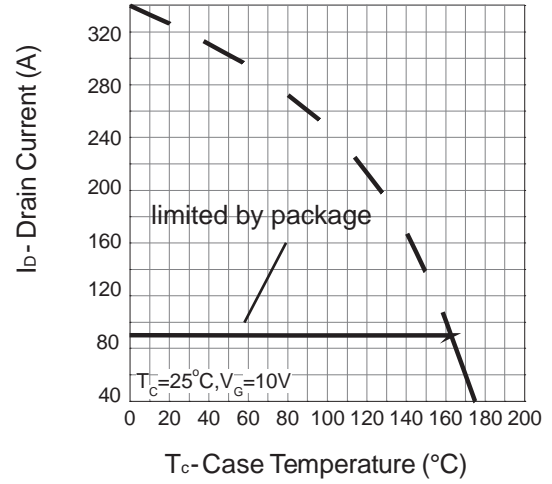
Note \* : Pulse test ; pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .

## Typical Operating Characteristics

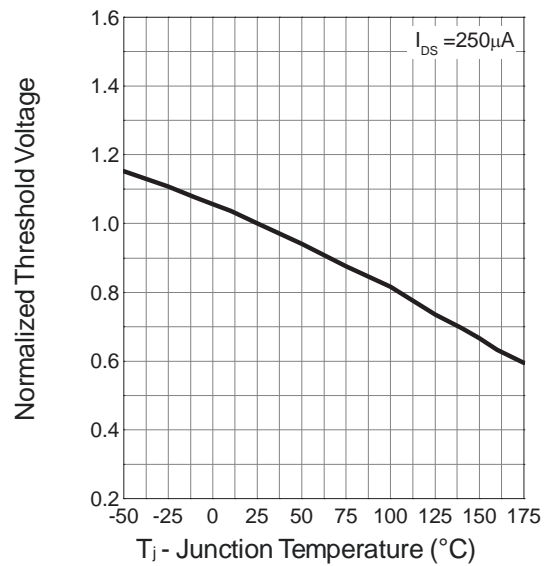
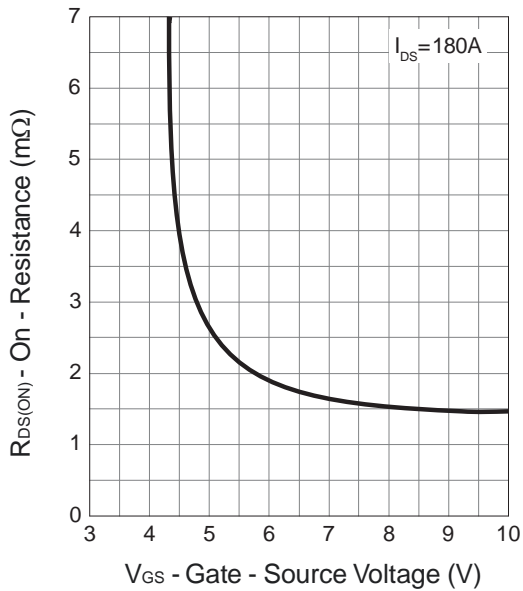
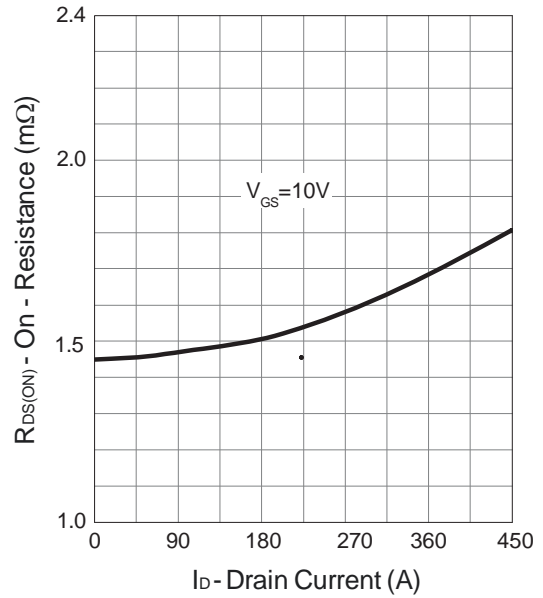
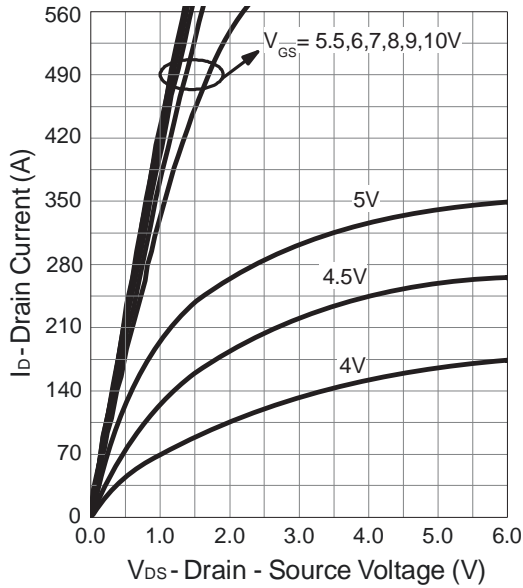
Power Dissipation



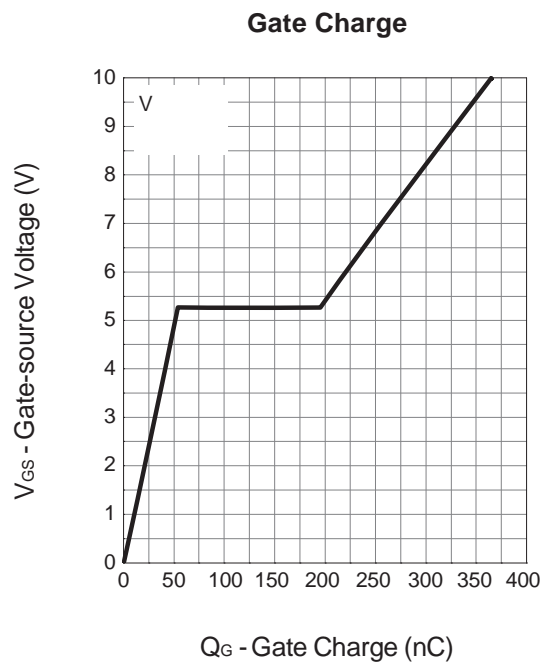
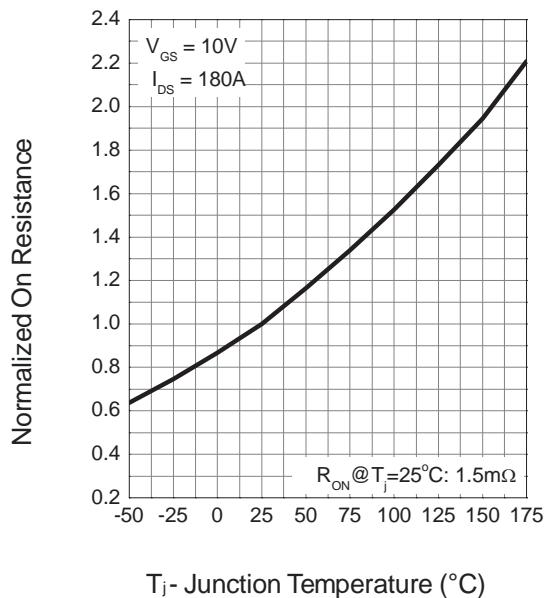
Drain Current



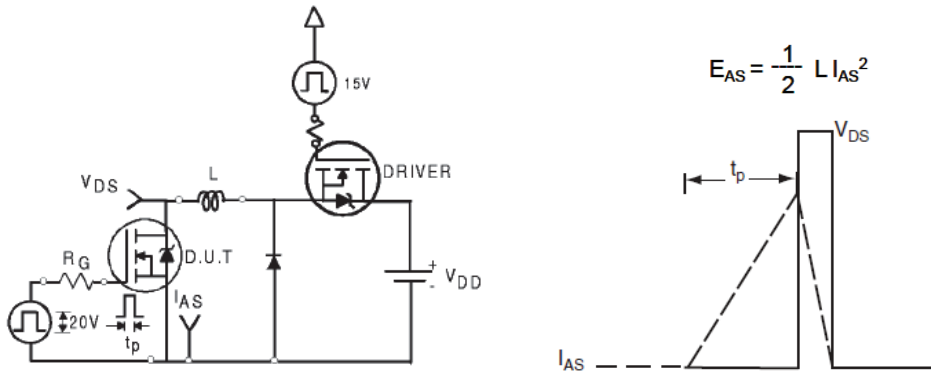
**Typical Operating Characteristics (Cont.)**



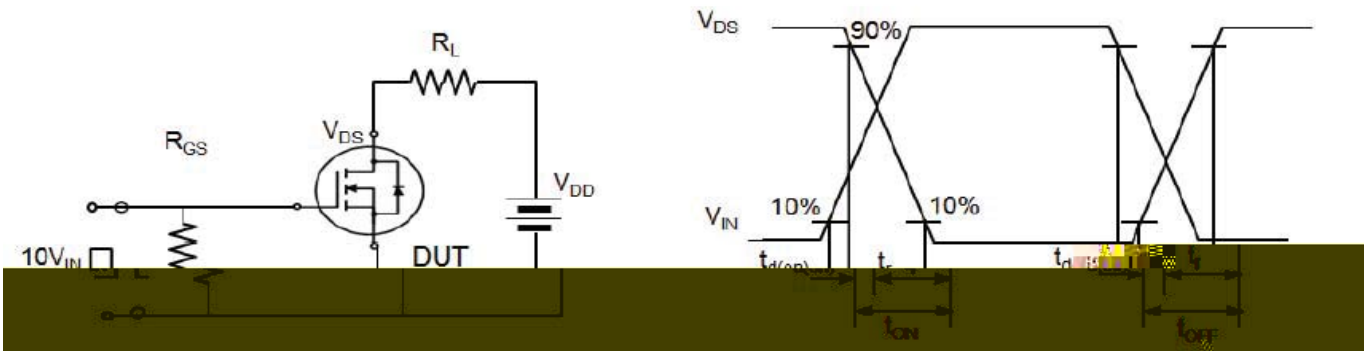
## Typical Operating Characteristics (Cont.)



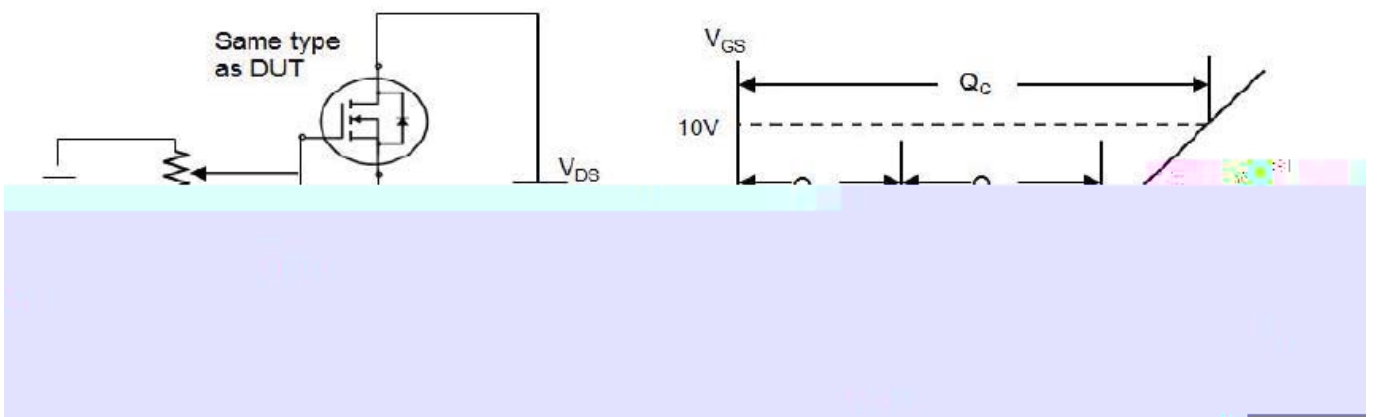
### Avalanche Test Circuit



### Switching Time Test Circuit



### Gate Charge Test Circuit



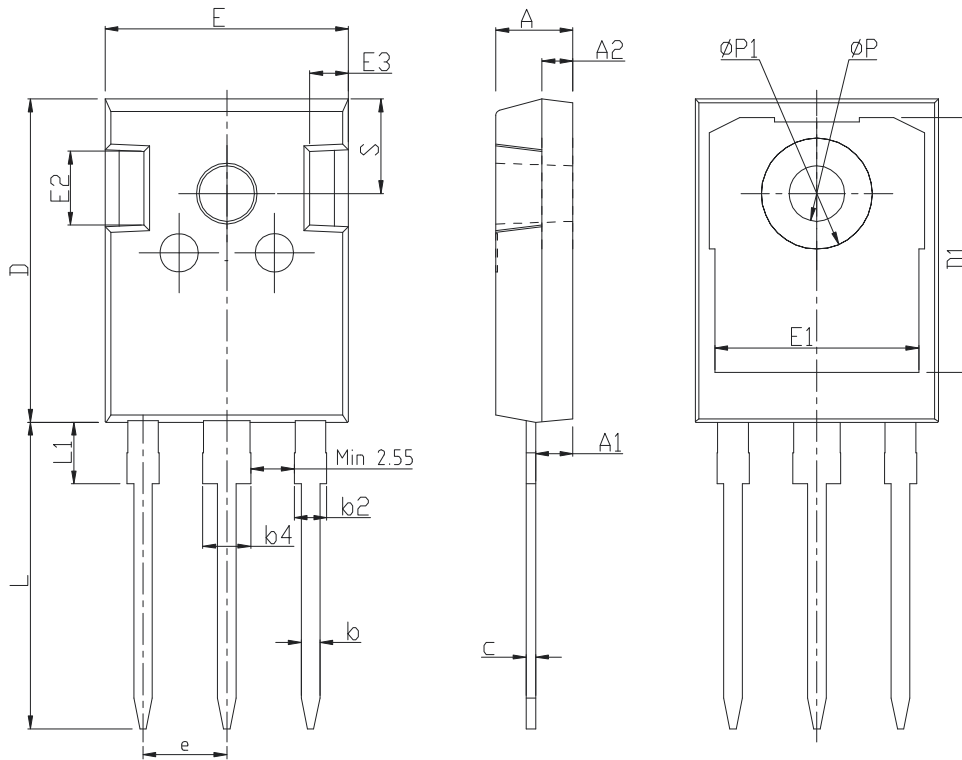
# HY5608W/A

## Device Per Unit

| Package Type | Unit | Quantity |
|--------------|------|----------|
| TO-247A-3L   | Tube | 30       |

## Package Information

TO-247A-3L



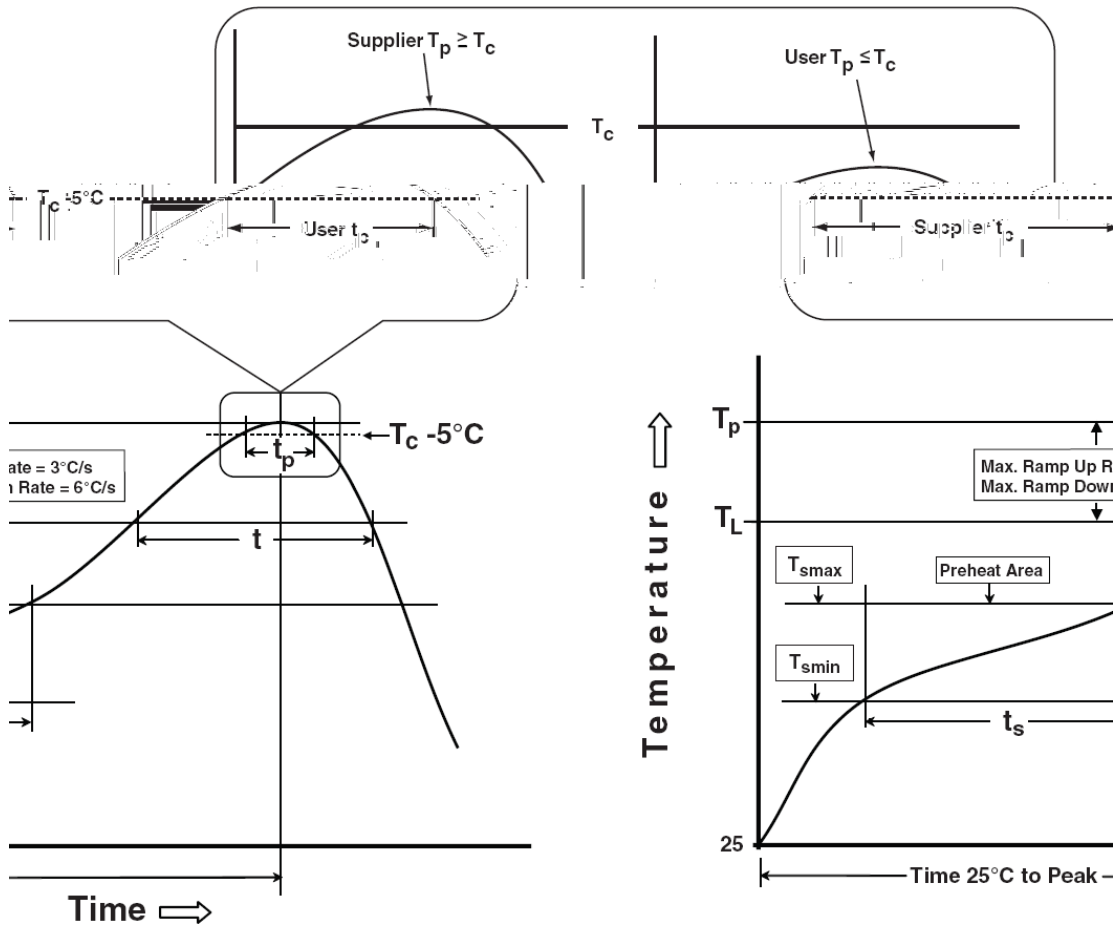
COMMON DIMEN



3P

3P

### Classification Profile



### Classification Reflow Profiles

| Profile Feature  | Sn-Pb Eutectic Assembly            | Pb-Free Assembly                   |
|--|------------------------------------|------------------------------------|
| <b>Preheat &amp; Soak</b>  |                                    |                                    |
| Temperature min ( $T_{smin}$ )   | 100 °C                             | 150 °C                             |
| Temperature max ( $T_{smax}$ )   | 150 °C                             | 200 °C                             |
| Time ( $T_{smin}$ to $T_{smax}$ ) ( $t_s$ )  | 60-120 seconds                     | 60-120 seconds                     |
| Average ramp-up rate ( $T_{smax}$ to $T_p$ )   | 3 °C/second max.                   | 3°C/second max.                    |
| Liquidous temperature ( $T_L$ )  | 183 °C                             | 217 °C                             |
| Time at liquidous ( $t_L$ )  | 60-150 seconds                     | 60-150 seconds                     |
| Peak package body Temperature ( $T_p$ )*   | See Classification Temp in table 1 | See Classification Temp in table 2 |
| Time ( $t_p$ )** within 5°C of the specified classification temperature ( $T_c$ )                                | 20** seconds                       | 30** seconds                       |
| Average ramp-down rate ( $T_p$ to $T_{smax}$ )   | 6 °C/second max.                   | 6 °C/second max.                   |
| Time 25°C to peak temperature  | 6 minutes max.                     | 8 minutes max.                     |
| * Tolerance for peak profile Temperature ( $T_p$ ) is defined as a supplier minimum and a user maximum.          |                                    |                                    |
| ** Tolerance for time at peak profile temperature ( $t_p$ ) is defined as a supplier minimum and a user maximum. |                                    |                                    |

# HY5608W/A

---

Table 1. SnPb Eutectic Process – Classification Temperatures (Tc)

**Package  
Thickness**

**Volume mm<sup>3</sup>  
<350**

**Volume mm<sup>3</sup>  
≥350**

Table 2. Pb-free Process – Classification Temperatures (Tc)

| <b>Package<br/>Thickness</b> | <b>Volume mm<sup>3</sup><br/>&lt;350</b> | <b>Volume mm<sup>3</sup><br/>350-2000</b> | <b>Volume mm<sup>3</sup><br/>&gt;2000</b> |
|------------------------------|--|---|---|
| <1.6 mm                      | 260 °C                                   | 260 °C                                    | 260 °C                                    |
| 1.6 mm – 2.5 mm              | 260 °C                                   | 250 °C                                    | 245 °C                                    |
| ≥2.5 mm                      | 250 °C                                   | 245 °C                                    | 245 °C                                    |